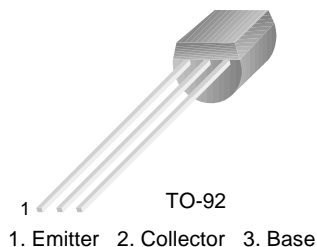


BC63916

BC63916

Switching and Amplifier Applications



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{CER}	Collector-Emitter Voltage at $R_{\text{BE}}=1\text{K}\Omega$	100	V
V_{CES}	Collector-Emitter Voltage	100	V
V_{CEO}	Collector-Emitter Voltage	80	V
V_{EBO}	Emitter-Base Voltage	5	V
I_{C}	Collector Current	1	A
P_{C}	Collector Power Dissipation	1	W
$T_{\text{J}}, T_{\text{STG}}$	Operating and Storage Junction Temperature Range	-55 ~ 150	$^\circ\text{C}$

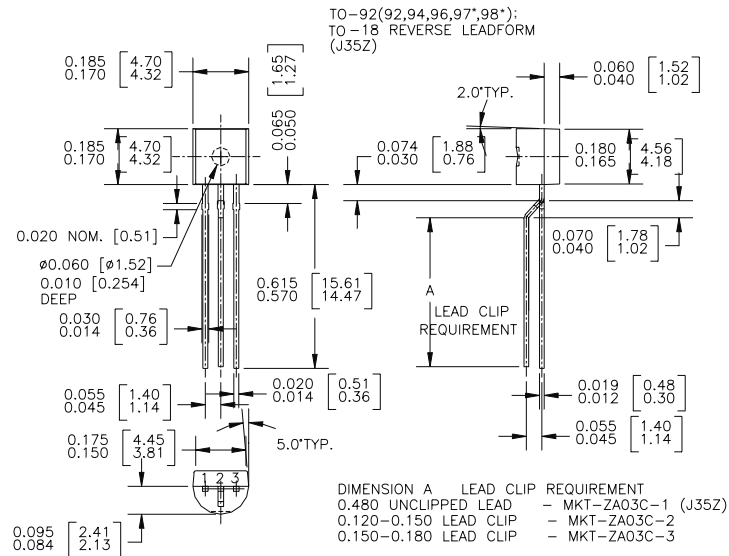
• $P_{\text{W}}=5\text{ms}$, Duty Cycle=10%

Electrical Characteristics $T_a=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
BV_{CBO}	Collector-Base Breakdown Voltage	$I_{\text{C}} = 100\mu\text{A}$, $I_{\text{E}} = 0$	100			V
BV_{CEO}	Collector-Emitter Breakdown Voltage	$I_{\text{C}} = 10\text{mA}$, $I_{\text{B}} = 0$	80			V
BV_{EBO}	Emitter-Base Breakdown Voltage	$I_{\text{E}} = 10\mu\text{A}$, $I_{\text{C}} = 0$	5.0			V
I_{CBO}	Collector Cut-off Current	$V_{\text{CB}} = 30\text{V}$, $I_{\text{E}} = 0$			100	nA
I_{EBO}	Emitter Cut-off Current	$V_{\text{EB}} = 5\text{V}$, $I_{\text{C}} = 0$			10	μA
h_{FE1} h_{FE2} h_{FE3}	DC Current Gain	$V_{\text{CE}} = 2\text{V}$, $I_{\text{C}} = 5\text{mA}$ $V_{\text{CE}} = 2\text{V}$, $I_{\text{C}} = 150\text{mA}$ $V_{\text{CE}} = 2\text{V}$, $I_{\text{C}} = 500\text{mA}$	25 100 25		250	
$V_{\text{CE(sat)}}$	Collector-Emitter Saturation Voltage	$I_{\text{C}} = 500\text{mA}$, $I_{\text{B}} = 50\text{mA}$			0.5	V
$V_{\text{BE(on)}}$	Base-Emitter On Voltage	$V_{\text{CE}} = 2\text{V}$, $I_{\text{C}} = 500\text{mA}$			1	V
f_{T}	Current Gain Bandwidth Product	$V_{\text{CE}} = 5\text{V}$, $I_{\text{C}}=10\text{mA}$, $f = 50\text{MHz}$		100		MHz

Package Dimensions

TO-92



Note: All package 97 or 98 transistors are leadformed to this configuration prior to bulk shipment. Order L34Z option if in-line leads are preferred on package 97 or 98.

* Standard Option on 97 & 98 package code

Dimensions in Millimeters

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